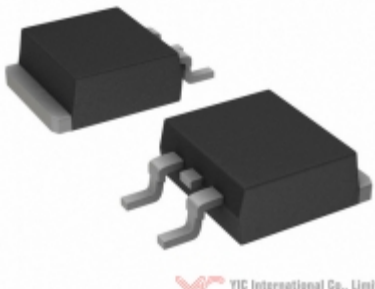

	<h2 style="color: #E67E22;">FQB44N10TM</h2>
 <p>Image may be representation. See specs for product details.</p>	<b>Hersteller-Teilenummer:</b> <a href="#">FQB44N10TM</a>
	<b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b> MOSFET N-CH 100V 43.5A D2PAK
	<b>Datenblätter:</b>  <a href="#">FQB44N10TM.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 34229 pcs Stock Available.
<b>Liefern von:</b> Hong Kong	
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	

### Spezifikationen

Teilenummer	<a href="#">FQB44N10TM</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 100V 43.5A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	34229 pcs Stock
Hersteller Standard Vorlaufzeit	28 Weeks
detaillierte Beschreibung	N-Channel 100V 43.5A (Tc) 3.75W (Ta), 146W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 146W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	43.5A (Tc)
Rds On (Max) @ Id, Vgs	39 mOhm @ 21.75A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	62nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1800pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Cut Tape (CT)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FQB44N10TMCT

FQB44N10TM ist neu im Original. Suche FQB44N10TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB44N10TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB44N10TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

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<b>FQB44N10</b> Fairchild FQB44N10 Fairchild	<b>FQB46N15TM</b> FSC FQB46N15TM FSC	<b>FQB46N15TM_AM002</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 45.6A D2PAK	<b>FQB3P50TM</b> Fairchild/ON Semiconductor MOSFET P-CH 500V 2.7A D2PAK
		 Not Actual Photo YIC International Co., Limited.	 Not Actual Photo YIC International Co., Limited.
<b>FQB45N15V2TM</b> Fairchild/ON Semiconductor MOSFET N-CH 150V 45A D2PAK	<b>FQB44N10TM</b> Fairchild/ON Semiconductor MOSFET N-CH 100V 43.5A D2PAK	<b>FQB41N15D</b> FAIRCHILD FAIRCHILD TO-263	<b>FQB46N15</b> F FQB46N15 F

heiße Teile

Mehr

⊛ FQB34N20L	↔ FQB34N20LTM	⇒ FQB34N20LTM	D FQB34N20TM	↔ FQB34N20TM_AM002
⊣ FQB34P10	⊛ FQB34P10TM	D FQB34P10TM	⇒ FQB34P10TM_F085	↔ FQB3N25TM
⊛ FQB3N25TM	⊣ FQB3N30TM	⊛ FQB3N30TM	↔ FQB3N40TM	↔ FQB3N40TM
D FQB3N60C	⊛ FQB3N80TM	⊣ FQB3N80TM	⊛ FQB3N90TM	↔ FQB3N90TM
⇒ FQB3P20TM	↔ FQB3P20TM	⊛ FQB3P50TM	⊣ FQB3P50TM	↔ FQB44N10
↔ FQB44N10TM	⇒ FQB46N15	D FQB46N15TM	⊛ FQB47P06	⊣ FQB47P06TM
⊛ FQB4N20L	D FQB4N20LTM	⇒ FQB4N20LTM	↔ FQB4N20TM	↔ FQB4N20TM
⊣ FQB4N25TM	⊛ FQB4N25TM	↔ FQB4N20TM	⇒ FQB4N50TM	↔ FQB4N50TM
⊛ FQB4N60C	⊣ FQB4N80TM	⊛ FQB4N80TM	D FQB4N90TM	↔ FQB4N90TM
↔ FQB4P25TM	⊛ FQB4P25TM	⊣ FQB50N03	⊛ FQB50N06	↔ FQB50N06C

Contact us:[Info@Y-IC.com](mailto:Info@Y-IC.com)

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